TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSVI)

TPCA8109

Lithium Ion Battery Applications Power Management Switch Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance: R_{DS} (ON) = 7 m Ω (typ.)
- Low leakage current: $IDSS = -10 \mu A (max) (VDS = -30 V)$
- Enhancement mode: $V_{th} = -0.8$ to -2.0 V ($V_{DS} = -10$ V, $I_{D} = -0.5$ mA)

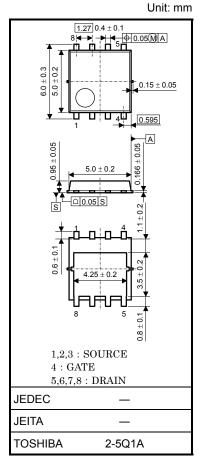
Absolute Maximum Ratings (Ta = 25°C)

| Characte | ristics | Symbol | Rating | Unit | |
|-----------------------|-------------------------------|------------------|------------|------|--|
| Drain-source voltage | | V_{DSS} | -30 | V | |
| Drain-gate voltage (R | $R_{GS} = 20 \text{ k}\Omega$ | V_{DGR} | -30 | V | |
| Gate-source voltage | | V _{GSS} | -25/+20 | V | |
| Drain current | DC (Note 1) | I _D | -24 | А | |
| | Pulsed (Note 1) | I_{DP} | -72 | | |
| Drain power dissipati | on (Tc=25°C) | P_{D} | 30 | W | |
| Drain power dissipati | on (t = 10 s) | PD | 2.8 | W | |
| | (Note 2a) | | 2.0 | VV | |
| Drain power dissipati | on (t = 10 s) | P _D | 1.6 | W | |
| | (Note 2b) | | 1.0 | V V | |
| Single pulse avalanch | ne energy | E _{AS} | 75 | mJ | |
| | (Note 3) | LA2 | 70 | 1110 | |
| Avalanche current | | I _{AR} | -24 | Α | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature | range | T _{stg} | –55 to 150 | °C | |

Note: For Notes 1 to 3, refer to the next page.

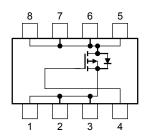
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic sensitive device. Please handle with caution.



Weight: 0.076 g (typ.)

Circuit Configuration

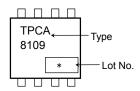


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Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|---|------------------------|------|------|
| Thermal resistance, channel to case (Tc=25°C) | R _{th (ch-c)} | 4.17 | °C/W |
| Thermal resistance, channel to ambient (t = 10 s) (Note 2a) | R _{th (ch-a)} | 44.6 | °C/W |
| Thermal resistance, channel to ambient (t = 10 s) (Note 2b) | R _{th (ch-a)} | 78.1 | °C/W |

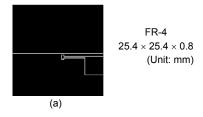
Marking (Note 4)

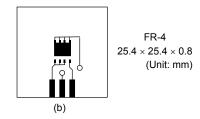


Note 1: Please use devices on condition that the channel temperature is below 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)

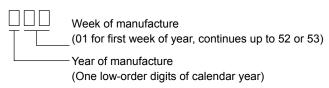
(b) Device mounted on a glass-epoxy board (b)





Note 3: $V_{DD} = -24~V$, $T_{ch} = 25^{\circ}C$ (initial), $L = 100 \mu H$, $R_G = 25~\Omega$, $I_{AR} = -24~A$

Note 4: * Weekly code: (Three digits)





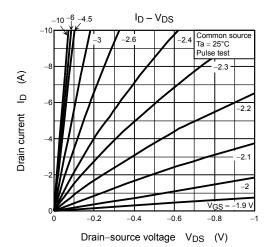
Electrical Characteristics (Ta = 25°C)

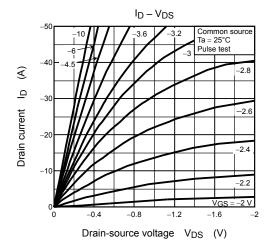
| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit | |
|---|----------------|-----------------------|--|---------|------|------|------|--|
| Gate leakage cur | rent | I _{GSS} | $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±100 | nA | |
| Drain cut-OFF cu | ırrent | I _{DSS} | $V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$ | _ | | | μА | |
| Drain-source breakdown voltage | | V _{(BR) DSS} | $I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$ | -30 | _ | _ | V | |
| Dialii-source brea | akdown voltage | V _{(BR) DSX} | $I_D = -10 \text{ mA}, V_{GS} = 10 \text{ V (Note5)}$ | -21 — — | | v | | |
| Gate threshold vo | oltage | V _{th} | $V_{DS} = -10 \text{ V}, I_D = -0.5 \text{ mA}$ | -0.8 | _ | -2.0 | V | |
| Drain-source ON resistance | | _ | $V_{GS} = -4.5V$, $I_D = -12 A$ | _ | 10 | 13 | mO | |
| | | NDS (ON) | $V_{GS} = -10 \text{ V}, I_D = -12 \text{ A}$ | _ | 7 | 9 | mΩ | |
| Input capacitance | 9 | C _{iss} | | | 2400 | _ | | |
| Reverse transfer | capacitance | C _{rss} | $V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$ | _ | 400 | _ | pF | |
| Output capacitance | | Coss | | _ | 460 | _ | | |
| Drain cut-OFF current IDSS V Drain-source breakdown voltage V (BR) DSS IDS V (BR) DSX IDS V (BR) DSX IDS V (BR) DSX IDS V (BR) DSX IDS IDS V (BR) DSX IDS V (BR) DSX V (BR) DSX | Rise time | t _r | V _{GS} 0 V 7 | _ | 9.2 | _ | | |
| | -10 V OUT G | _ | 16 | _ | | | | |
| Switching time | Fall time | t _f | $V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{GS} = -10 \text{ V}$ $V_{DD} = -12 \text{ A}$ $V_{OUT} = 0 \text{ V}$ $V_{DD} \approx -15 \text{ V}$ $V_{DU} \approx 1\%, t_W = 10 \mu\text{s}$ | _ | 58 | _ | ns | |
| | Turn-off time | | | _ | 172 | _ | | |
| | | | $V_{DD} \approx -24 \text{ V}, V_{GS} = -10 \text{ V},$ $I_D = -24 \text{ A}$ | _ | 56 | | nC | |
| Gate-source charge 1 | | Q _{gs1} | | | 5.6 | | | |
| Gate-drain ("miller") charge | | Q _{gd} | | _ | 15 | _ | | |

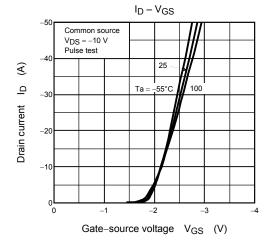
Source-Drain Ratings and Characteristics (Ta = 25°C)

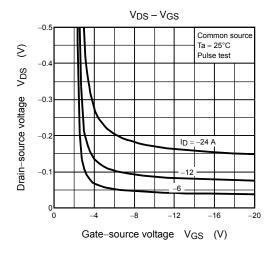
| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit | |
|-------------------------|-------|----------|------------------|--|------|-----|------|---|
| Drain reverse current | Pulse | (Note 1) | I _{DRP} | _ | _ | _ | -72 | Α |
| Forward voltage (diode) | | | V _{DSF} | $I_{DR} = -24 \text{ A}, V_{GS} = 0 \text{ V}$ | _ | _ | 1.2 | V |

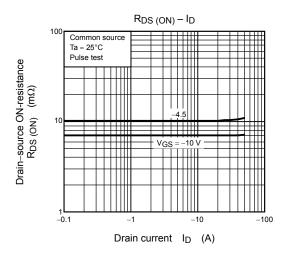
Note 5: $V_{(BR)DSX}$ mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.



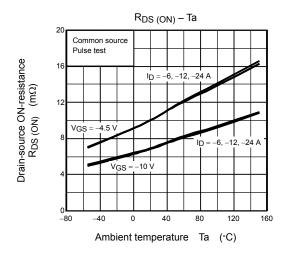


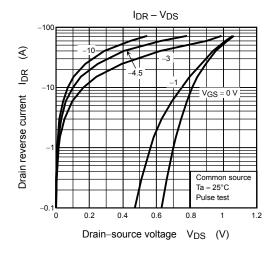


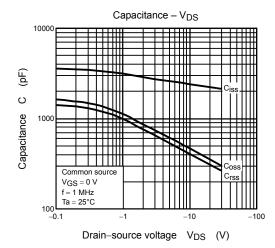


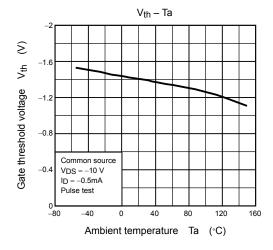


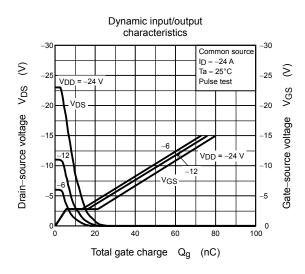
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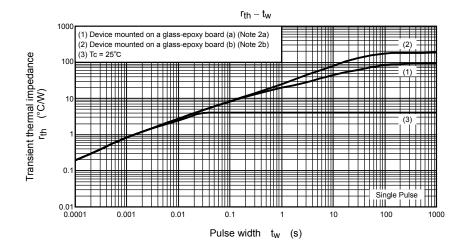


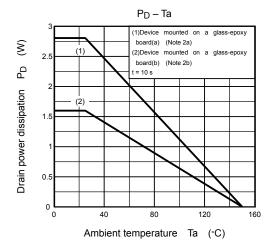


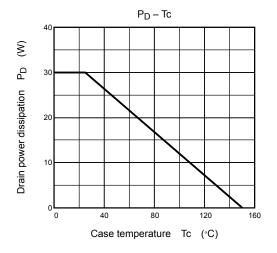


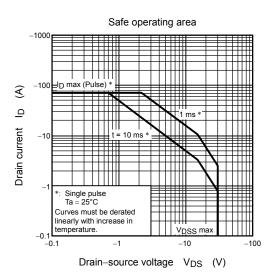


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